

AMENDMENTS TO THE SPECIFICATION

Please replace the first full paragraph on page 18 with the following amended paragraph:

The undoped n-type (111) boron phosphide layer serving as the lower cladding layer 102 was found to have a carrier (hole)-(electron) concentration of $6 \times 10^{19} \text{ cm}^{-3}$ and a resistivity at room temperature of $8 \times 10^{-3} \Omega\cdot\text{cm}$. The undoped p-type (111) boron phosphide layer serving as the upper cladding layer 104 was found to have a carrier (hole) concentration of $2 \times 10^{19} \text{ cm}^{-3}$ and a resistivity at room temperature of $5 \times 10^{-2} \Omega\cdot\text{cm}$.